

International **IR** Rectifier

50WQ03F

50WQ04F

SCHOTTKY RECTIFIER

5.5 Amp

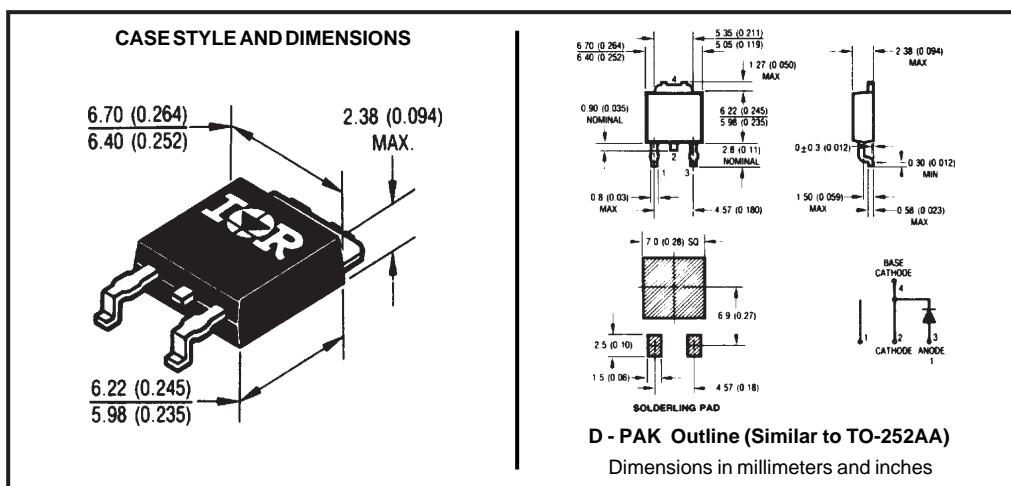
Major Ratings and Characteristics

Characteristics	50WQ..F	Units
$I_{F(AV)}$ Rectangular waveform	5.5	A
V_{RRM}	30/40	V
I_{FSM} @ 60Hz	470	A
V_F @ 5Apk, $T_J = 25^\circ\text{C}$	0.65	V
T_J	-40 to 125	°C

Description/Features

The 50WQ..F surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



50WQ03F, 50WQ04F

PD-2.310 rev. A 12/97

International
IR Rectifier

Voltage Ratings

Part number	50WQ03F	50WQ04F
V_R Max. DC Reverse Voltage (V)		
V_{RWM} Max. Working Peak Reverse Voltage (V)	30	40

Absolute Maximum Ratings

Parameters	50WQ..F	Units	Conditions	
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	5.5	A	50% duty cycle @ $T_c = 92^\circ\text{C}$, rectangular waveform	
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	470	A	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V_{RWM} applied
	42		10ms Sine or 6ms Rect. pulse	

Electrical Specifications

Parameters	50WQ..F	Units	Conditions	
V_{FM} Max. Forward Voltage Drop * See Fig. 1 (1)	0.65	V	@ 5A	$T_J = 25^\circ\text{C}$
	0.90	V	@ 10A	
	0.60	V	@ 5A	$T_J = 125^\circ\text{C}$
	0.78	V	@ 10A	
I_{RM} Max. Reverse Leakage Current * See Fig. 2 (1)	3	mA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_R$
	20	mA	$T_J = 125^\circ\text{C}$	
C_T Typical Junction Capacitance	180	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz)	25°C
L_S Typical Series Inductance	5.0	nH	Measured lead to lead 5mm from package body	

(1) Pulse Width < 300μs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	50WQ..F	Units	Conditions	
T_J Max. Junction Temperature Range	-40 to 125	°C		
T_{stg} Max. Storage Temperature Range	-40 to 125	°C		
R_{thJC} Max. Thermal Resistance Junction to Case	6.0	°C/W	DC operation	* See Fig. 4
wt Approximate Weight	0.3(0.01)	g(oz.)		
Case Style	D-PAK		Similar to TO-252AA	

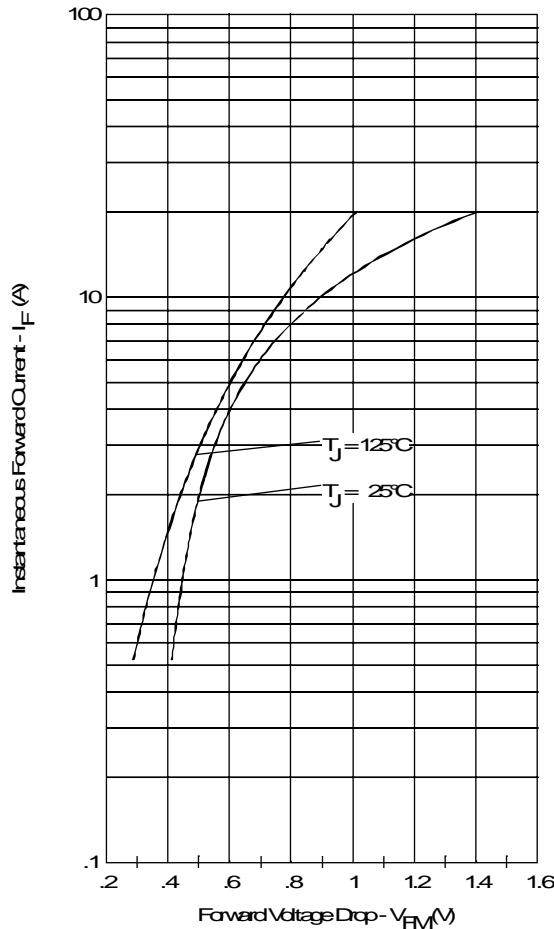


Fig. 1-Maximum Forward Voltage Drop Characteristics

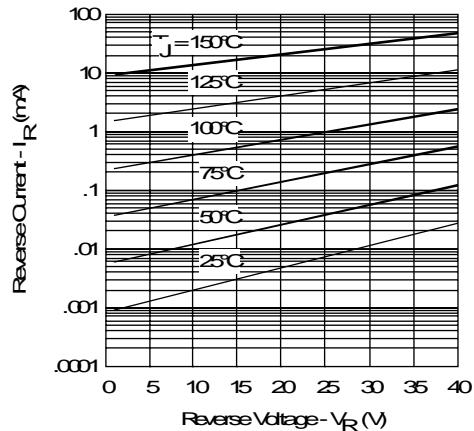


Fig. 2-Typical Values of Reverse Current Vs. Reverse Voltage

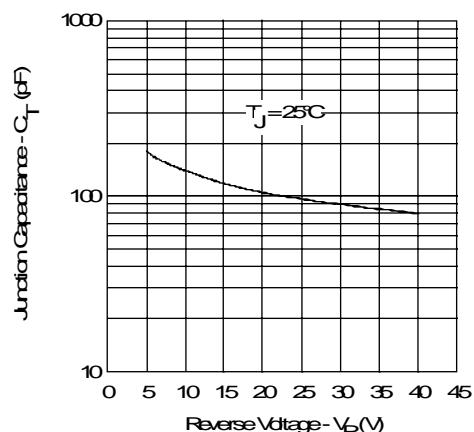


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

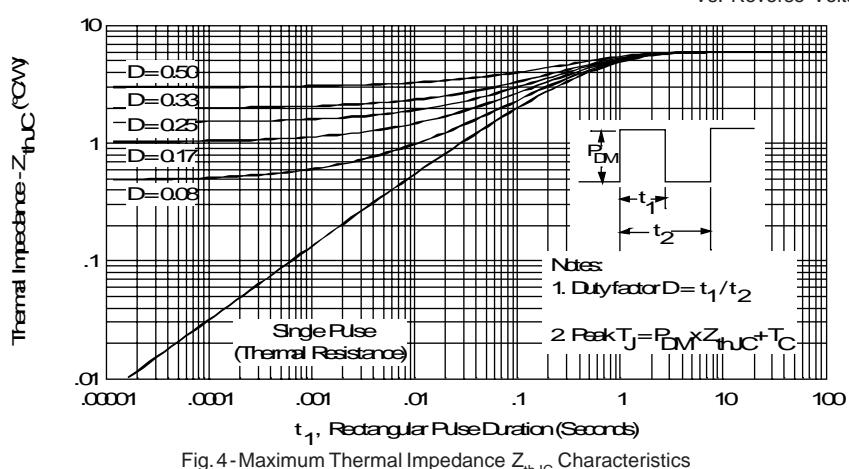


Fig. 4-Maximum Thermal Impedance Z_{thJC} Characteristics

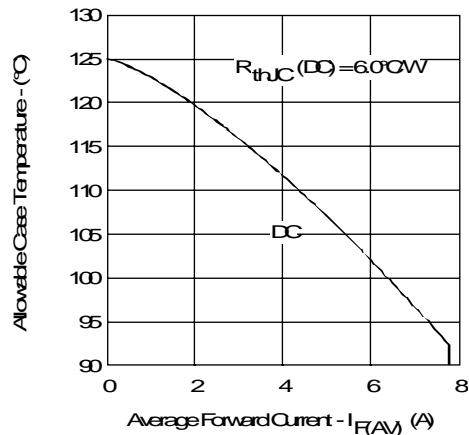


Fig.5-Maximum Allowable Case Temperature Vs. Average Forward Current

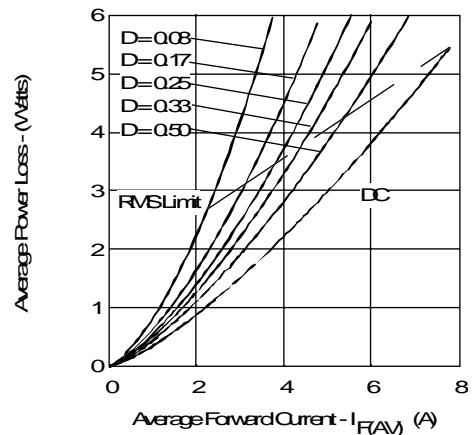


Fig.6-Forward Power Loss Characteristics

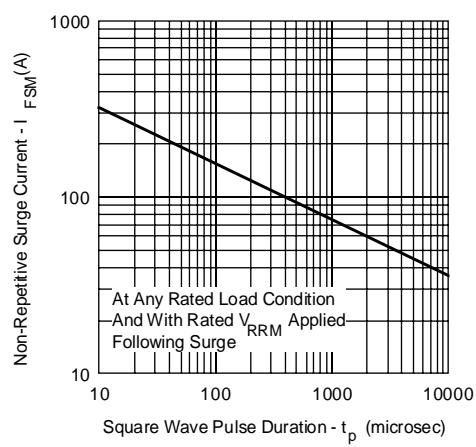


Fig.7-Maximum Non-Repetitive Surge Current